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STTH9012TV

Ultrafast recovery - 1200 V diode

Main product characteristics

I _{F(AV)}	2 x 45 A
V _{RRM}	1200 V
T _j	150° C
V _F (typ)	1.20 V
t _{rr} (typ)	50 ns

Features and benefits

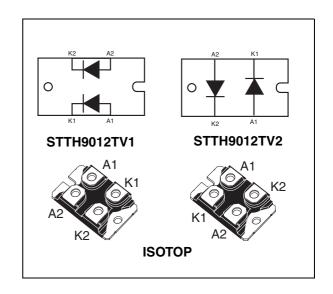
- Ultrafast, soft recovery
- Very low conduction and switching losses
- High frequency and/or high pulsed current operation
- High reverse voltage capability
- High junction temperature
- Insulated package: Electrical insulation = 2500 V_{RMS} Capacitance = 45 pF

Description

The high quality design of this diode has produced a device with low leakage current, regularly reproducible characteristics and intrinsic ruggedness. These characteristics make it ideal for heavy duty applications that demand long term reliability.

Such demanding applications include industrial power supplies, motor control, and similar mission-critical systems that require rectification and freewheeling. These diodes also fit into auxiliary functions such as snubber, bootstrap, and demagnetization applications.

The improved performance in low leakage current, and therefore thermal runaway guard band, is an immediate competitive advantage for this device.



Order codes

Part Number	Marking
STTH9012TV1	STTH9012TV1
STTH9012TV2	STTH9012TV2

Characteristics STTH9012TV

Characteristics 1

Absolute ratings (limiting values per diode at 25° C, unless otherwise specified) Table 1.

Symbol	Parameter			Value	Unit
V _{RRM}	Repetitive peak reverse voltage	Repetitive peak reverse voltage			V
I _{F(RMS)}	RMS forward current			150	Α
I _{F(AV)}	Average forward current, $\delta = 0.5$		T _c = 75° C per diode	45	Α
I _{FRM}	Repetitive peak forward current	t _p = 5 μs, F = 5 kHz square		600	Α
I _{FSM}	Surge non repetitive forward current	t _p = 10 ms Sinusoidal		420	Α
T _{stg}	Storage temperature range			-65 to + 150	°C
T _j	Maximum operating junction temperature			150	°C

Table 2. **Thermal parameters**

Symbol	Parameter		Value	Unit
D	Junction to case	Per diode	Per diode 0.74	
R _{th(j-c)}	Junction to case	Total	0.42	°C/W
R _{th(c)}	Coupling thermal resistance		0.1	

When the diodes are used simultaneously:

 $\Delta T_{j(diode1)} = P_{(diode1)} x R_{th(j-c)}$ (per diode) + $P_{(diode2)} x R_{th(c)}$

Table 3. Static electrical characteristics

Symbol	Parameter	Test conditions		Min.	Тур	Max.	Unit
I _R ⁽¹⁾	Reverse leakage current	T _j = 25° C	V - V			30	
IR''' Heverse leak	neverse leakage current	$T_j = 125^{\circ} \text{ C}$ $V_R = V_{RRM}$		30	300	μA	
		T _j = 25° C				2.10	
V _F ⁽²⁾	Forward voltage drop	T _j = 125° C	I _F = 45 A		1.25	1.90	V
		T _j = 150° C			1.20	1.80	

^{1.} Pulse test: t_p = 5 ms, δ < 2 %

To evaluate the conduction losses use the following equation: P = 1.40 x $I_{F(AV)}$ + 0.0089 I_{F}^{2} _(RMS)

$$P = 1.40 \text{ x } I_{F(AV)} + 0.0089 I_{F^2(RMS)}$$

^{2.} Pulse test: t_p = 380 μ s, δ < 2 %

STTH9012TV Characteristics

Table 4. Dynamic characteristics

Symbol	Parameter	Test conditions	Min.	Тур	Max.	Unit
		$I_F = 1 \text{ A, } dI_F/dt = -50 \text{ A/}\mu\text{s,}$ $V_R = 30 \text{ V, } T_j = 25^{\circ} \text{ C}$			125	
t _{rr}	Reverse recovery time	I_F = 1 A, dI_F/dt = -100 A/ μ s, V_R = 30 V, T_j = 25° C		63	85	ns
		I_F = 1 A, dI_F/dt = -200 A/ μ s, V_R = 30 V, T_j = 25° C		50	70	
I _{RM}	Reverse recovery current	$I_F = 45 \text{ A}, dI_F/dt = -200 \text{ A/}\mu\text{s},$ $V_R = 600 \text{ V}, T_j = 125^{\circ} \text{ C}$		32	45	Α
S	Softness factor	$I_F = 45 \text{ A}, dI_F/dt = -200 \text{ A/}\mu\text{s},$ $V_R = 600 \text{ V}, T_j = 125^{\circ} \text{ C}$		1		
t _{fr}	Forward recovery time	$I_F = 45 \text{ A}$ $dI_F/dt = 100 \text{ A/}\mu\text{s}$ $V_{FR} = 1.5 \text{ x } V_{Fmax}, T_j = 25^{\circ} \text{ C}$			700	ns
V _{FP}	Forward recovery voltage	$I_F = 45 \text{ A}, dI_F/dt = 100 \text{ A/}\mu\text{s},$ $T_j = 25^{\circ} \text{ C}$		4.5		V

Figure 1. Conduction losses versus average current

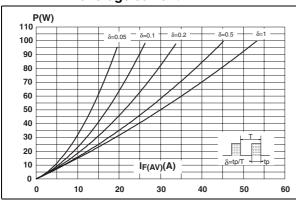
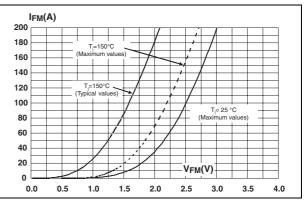


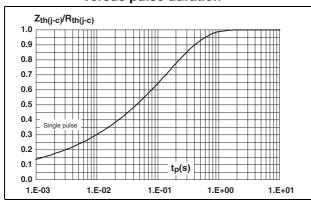
Figure 2. Forward voltage drop versus forward current



Characteristics STTH9012TV

Figure 3. Relative variation of thermal impedance junction to case versus pulse duration

Figure 4. Peak reverse recovery current versus dl_F/dt (typical values)



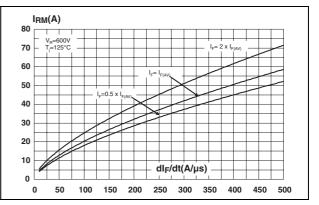
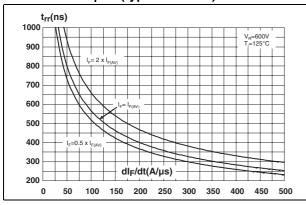


Figure 5. Reverse recovery time versus dl_F/dt (typical values)

Figure 6. Reverse recovery charges versus dl_F/dt (typical values)



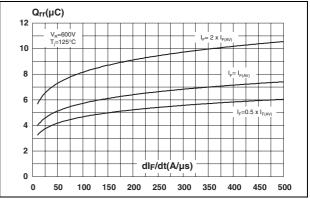
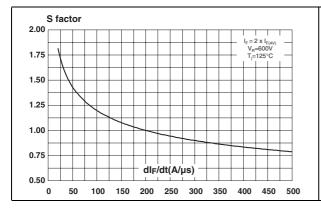
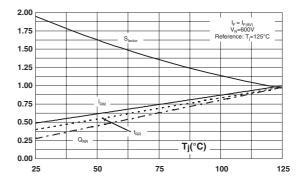


Figure 7. Softness factor versus dl_F/dt (typical values)

Figure 8. Relative variations of dynamic parameters versus junction temperature

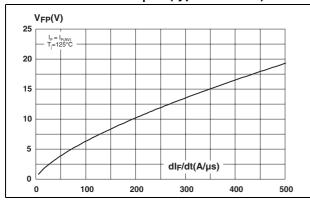




STTH9012TV Characteristics

Figure 9. Transient peak forward voltage versus dl_F/dt (typical values)

Figure 10. Forward recovery time versus dl_F/dt (typical values)



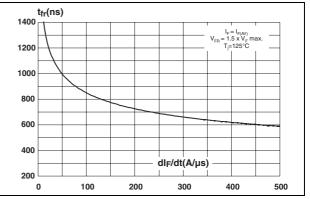
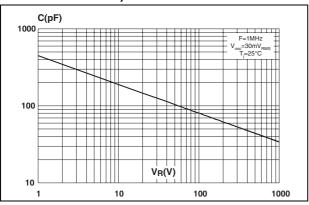


Figure 11. Junction capacitance versus reverse voltage applied (typical values)



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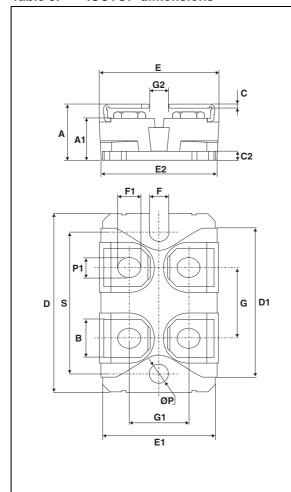
Package information STTH9012TV

2 Package information

Epoxy meets UL94, V0

Cooling method: by conduction (C)

Table 5. ISOTOP dimensions



	DIMENSIONS				
REF.	Millimeters		Inc	hes	
	Min.	Max	Min.	Max.	
Α	11.80	12.20	0.465	0.480	
A1	8.90	9.10	0.350	0.358	
В	7.8	8.20	0.307	0.323	
С	0.75	0.85	0.030	0.033	
C2	1.95	2.05	0.077	0.081	
D	37.80	38.20	1.488	1.504	
D1	31.50	31.70	1.240	1.248	
Е	25.15	25.50	0.990	1.004	
E1	23.85	24.15	0.939	0.951	
E2	24.80	4.80 typ. 0.97		'6 typ.	
G	14.90	15.10	0.587	0.594	
G1	12.60	12.80	0.496	0.504	
G2	3.50	4.30	0.138	0.169	
F	4.10	4.30	0.161	0.169	
F1	4.60	5.00	0.181	0.197	
Р	4.00	4.30	0.157	0.69	
P1	4.00	4.40	0.157	0.173	
S	30.10	30.30	1.185	1.193	

In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com.

3 Ordering information

Part Number	Marking	Package	Weight	Base qty	Delivery mode
STTH9012TV1	STTH9012TV1	ISOTOP	27 g	10	Tube
STTH9012TV2	STTH9012TV2	ISOTOP	27 g	10	Tube

4 Revision history

Date	Revision	Description of Changes
02-Mar-2006	1	First issue.

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